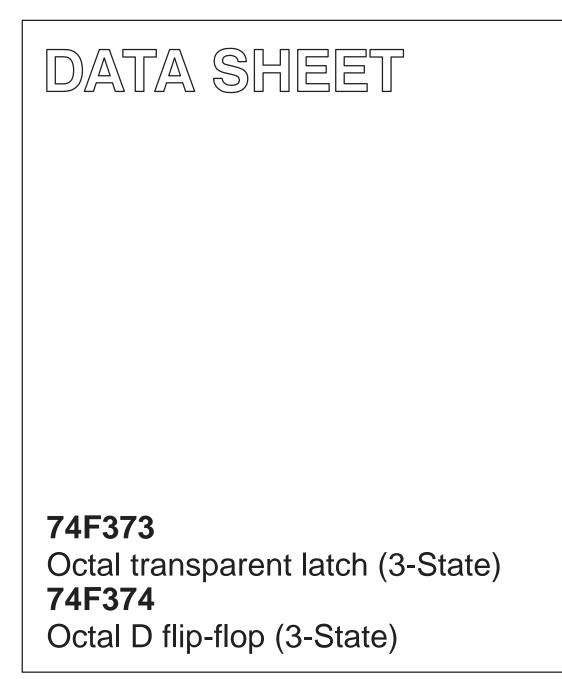
INTEGRATED CIRCUITS



Product data Supersedes data of 1994 Dec 05 2002 Nov 20



Latch/flip-flop

74F373 Octal transparent latch (3-State) 74F374 Octal D-type flip-flop (3-State)

FEATURES

- 8-bit transparent latch 74F373
- 8-bit positive edge triggered register 74F374
- 3-State outputs glitch free during power-up and power-down
- Common 3-State output register
- Independent register and 3-State buffer operation
- SSOP Type II Package

DESCRIPTION

The 74F373 is an octal transparent latch coupled to eight 3-State output devices. The two sections of the device are controlled independently by enable (E) and output enable (\overline{OE}) control gates.

The data on the D inputs is transferred to the latch outputs when the enable (E) input is HIGH. The latch remains transparent to the data input while E is HIGH, and stores the data that is present one set-up time before the HIGH-to-LOW enable transition.

The 3-State output buffers are designed to drive heavily loaded 3-State buses, MOS memories, or MOS microprocessors.

The active-LOW output enable (\overline{OE}) controls all eight 3-State buffers independent of the latch operation. When \overline{OE} is LOW, latched or transparent data appears at the output.

When OE is HIGH, the outputs are in high impedance "off" state, which means they will neither drive nor load the bus.

The 74F374 is an 8-bit edge triggered register coupled to eight 3-State output buffers. The two sections of the device are controlled independently by clock (CP) and output enable (OE) control gates.

The register is fully edge triggered. The state of the D input, one set-up time before the LOW-to-HIGH clock transition is transferred to the corresponding flip-flop's Q output.

The 3-State output buffers are designed to drive heavily loaded 3-State buses, MOS memories, or MOS microprocessors.

The active-LOW output enable (\overline{OE}) controls all eight 3-State buffers independent of the register operation. When \overline{OE} is LOW, the data in the register appears at the outputs. When \overline{OE} is HIGH, the outputs are in high impedance "off" state, which means they will neither drive nor load the bus.

ТҮРЕ	TYPICAL PROPAGATION DELAY	TYPICAL SUPPLY CURRENT (TOTAL)
74F373	4.5 ns	35 mA

ТҮРЕ	TYPICAL f _{max}	TYPICAL SUPPLY CURRENT (TOTAL)			
74F374	165 MHz	55 mA			

ORDERING INFORMATION

	ORDER CODE	
DESCRIPTION	COMMERCIAL RANGE V _{CC} = 5 V \pm 10%, T _{amb} = 0 °C to +70 °C	PKG DWG #
20-pin plastic DIP	N74F373N, N74F374N	SOT146-1
20-pin plastic SOL	N74F373D, N74F374D	SOT163-1
20-pin plastic SSOP type II	N74F373DB, N74F374DB	SOT339-1

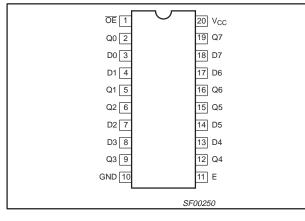
INPUT AND OUTPUT LOADING AND FAN OUT TABLE

PINS	DESCRIPTION	74F (U.L.) HIGH / LOW	LOAD VALUE HIGH/LOW
D0 - D7	Data inputs	1.0 / 1.0	20 µA / 0.6 mA
E (74F373)	Enable input (active-HIGH)	1.0 / 1.0	20 µA / 0.6 mA
OE	Output enable inputs (active-LOW)	1.0 / 1.0	20 µA / 0.6 mA
CP (74F374)	Clock pulse input (active rising edge)	1.0 / 1.0	20 µA / 0.6 mA
Q0 - Q7	3-State outputs	150 / 40	3.0 mA / 24 mA

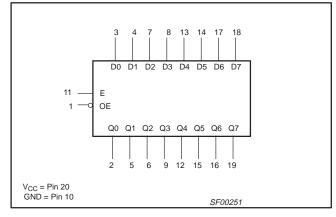
NOTE: One (1.0) FAST unit load is defined as: 20 µA in the HIGH state and 0.6 mA in the LOW state.

Product data

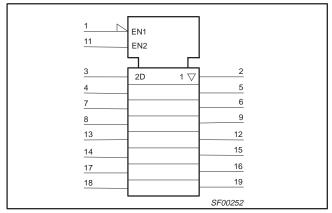
PIN CONFIGURATION – 74F373



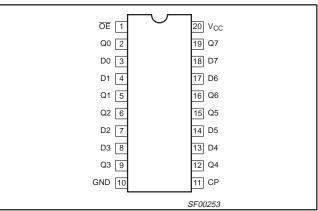
LOGIC SYMBOL - 74F373



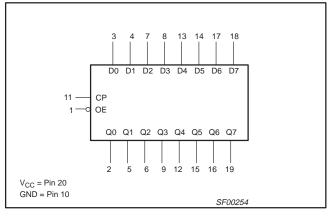
IEC/IEEE SYMBOL - 74F373



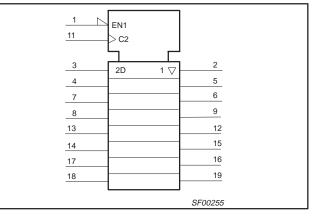
PIN CONFIGURATION – 74F374



IEC/IEE SYMBOL – 74F374

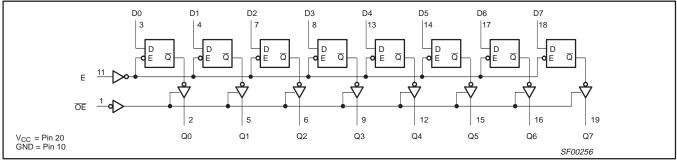


IEC/IEEE SYMBOL – 74F374

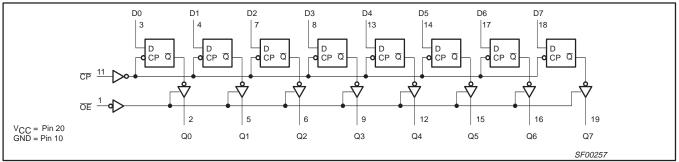


74F373/74F374

LOGIC DIAGRAM FOR 74F373



LOGIC DIAGRAM FOR 74F374



FUNCTION TABLE FOR 74F373

	INPUTS		INTERNAL	OUTPUTS	OPERATING MODE
OE	E	Dn	REGISTER	Q0 - Q7	OPERATING MODE
L	Н	L	L	L	Enable and read register
L	Н	Н	Н	Н	Enable and read register
L	\downarrow	I	L	L	Lateband read register
L	\downarrow	h	н	н	Latch and read register
L	L	Х	NC	NC	Hold
Н	L	Х	NC	Z	
Н	Н	Dn	Dn	Z	Disable outputs

NOTES:

H = High-voltage level

HIGH state must be present one set-up time before the HIGH-to-LOW enable transition h =

L Low-voltage level =

LOW state must be present one set-up time before the HIGH-to-LOW enable transition Т =

NC= No change

 $X = Z = \downarrow =$ Don't care

High impedance "off" state

HIGH-to-LOW enable transition

FUNCTION TABLE FOR 74F374

	INPUTS		INTERNAL	OUTPUTS				
OE	СР	Dn	REGISTER	Q0 – Q7	OPERATING MODE			
L	↑	I	L	L	Load and read register			
L	↑	h	Н	Н	Load and read register			
L	\$	Х	NC	NC	Hold			
Н	\$	Х	NC	Z	Dischle outputs			
н	↑	Dn	Dn	Z	Disable outputs			

NOTES:

H = High-voltage level

HIGH state must be present one set-up time before the LOW-to-HIGH clock transition h =

L = Low-voltage level

L = LOW state must be present one set-up time before the LOW-to-HIGH clock transition

NC= No change

Х = Don't care

High impedance "off" state =

Z ↑ LOW-to-HIGH clock transition =

≏ = Not LOW-to-HIGH clock transition

ABSOLUTE MAXIMUM RATINGS

Operation beyond the limit set forth in this table may impair the useful life of the device. Unless otherwise noted these limits are over the operating free air temperature range.

SYMBOL	PARAMETER	RATING	UNIT
V _{CC}	Supply voltage	-0.5 to +7.0	V
V _{IN}	Input voltage	-0.5 to +7.0	V
I _{IN}	Input current	-30 to +5	mA
V _{OUT}	Voltage applied to output in HIGH output state	–0.5 to V_{CC}	V
I _{OUT}	Current applied to output in LOW output state	48	mA
T _{amb}	Operating free air temperature range	0 to +70	°C
T _{stg}	Storage temperature range	-65 to +150	°C

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER		UNIT		
STWBUL	PARAMEIER	MIN	NOM	MAX	UNIT
V _{CC}	Supply voltage	4.5	5.0	5.5	V
V _{IH}	HIGH-level input voltage	2.0	-	-	V
V _{IL}	LOW-level input voltage	-	-	0.8	V
I _{lk}	Input clamp current	-	-	-18	mA
I _{OH}	HIGH-level output current	-	-	-3	mA
I _{OL}	LOW-level output current	-	-	24	mA
T _{amb}	Operating free air temperature range	0	-	+70	°C

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DC ELECTRICAL CHARACTERISTICS

(Over recommended operating free-air temperature range unless otherwise noted.)

SYMBOL	DADAMETED		TEST					
SYMBOL	PARAMETER		CONDITIONS ¹	MIN	TYP ²	MAX		
V			V _{CC} = MIN, V _{IL} = MAX,	$\pm 10\% V_{CC}$	2.4			V
V _{OH}	HIGH-level output voltage		$V_{IH} = MIN, I_{OH} = MAX$	±5%V _{CC}	2.7	3.4		V
M			V _{CC} = MIN, V _{IL} = MAX,	$\pm 10\% V_{CC}$		0.35	0.50	V
V _{OL}	LOW-level output voltage		$V_{IH} = MIN, I_{OL} = MAX$	±5%V _{CC}		0.35	0.50	V
V _{IK}	Input clamp voltage	$V_{CC} = MIN, I_I = I_{IK}$		-0.73	-1.2	V		
I _I	Input current at maximum input voltage	Input current at maximum input voltage					100	μΑ
I _{IH}	High-level input current		$V_{CC} = MAX, V_I = 2.7 V$			20	μΑ	
IIL	Low-level input current		$V_{CC} = MAX, V_I = 0.5 V$				-0.6	mA
I _{OZH}	Off-state output current, high-level voltage ap	plied	V_{CC} = MAX, V_{O} = 2.7 V			50	μΑ	
I _{OZL}	Off-state output current, low-level voltage app	olied	V_{CC} = MAX, V_{O} = 0.5 V			-50	μΑ	
I _{OS}	Short-circuit output current ³	V _{CC} = MAX	-60		-150	mA		
I _{CC}	Supply current (total)	74F373	V _{CC} = MAX			35	60	mA
					57	86	mA	

NOTES:

1. For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions for the applicable type. 2. All typical values are at $V_{CC} = 5 \text{ V}$, $T_{amb} = 25 \text{ °C}$. 3. Not more than one output should be shorted at a time. For testing I_{OS} , the use of high-speed test apparatus and/or sample-and-hold techniques are preferable in order to minimize internal heating and more accurately reflect operational values. Otherwise, prolonged shorting of a high output may raise the chip temperature well above normal and thereby cause invalid readings in other parameter tests. In any sequence of parameter tests, I_{OS} tests should be performed last.

AC ELECTRICAL CHARACTERISTICS

						LIN	NITS		
SYMBOL	PARAMETER		TEST CONDITION	v _o	_{nb} = +25 _{CC} = +5.0) pF; R _L :	V	T _{amb} = 0 °C V _{CC} = +5.0 C _L = 50 pF;	UNIT	
				MIN	TYP	MAX	MIN	MAX	
t _{PLH} t _{PHL}	Propagation delay Dn to Qn		Waveform 3	3.0 2.0	5.3 3.7	7.0 5.0	3.0 2.0	8.0 6.0	ns
t _{PLH} t _{PHL}	Propagation delay E to Qn	74F373	Waveform 2	5.0 3.0	9.0 4.0	11.5 7.0	5.0 3.0	12.0 8.0	ns
t _{PZH} t _{PZL}	Output enable time to HIGH or LOW level		Waveform 6 Waveform 7	2.0 2.0	5.0 5.6	11.0 7.5	2.0 2.0	11.5 8.5	ns
t _{PHZ} t _{PLZ}	Output disable time from HIGH or LOW level		Waveform 6 Waveform 7	2.0 2.0	4.5 3.8	6.5 5.0	2.0 2.0	7.0 6.0	ns
f _{max}	Maximum clock frequency		Waveform 1	150	165		140		ns
t _{PLH} t _{PHL}	Propagation delay CP to Qn	74F374	Waveform 1	3.5 3.5	5.0 5.0	7.5 7.5	3.0 3.0	8.5 8.5	ns
t _{PZH} t _{PZL}	Output enable time to HIGH or LOW level		Waveform 6 Waveform 7	2.0 2.0	9.0 5.3	11.0 7.5	2.0 2.0	12.0 8.5	ns
t _{PHZ} t _{PLZ}	Output disable time from HIGH or LOW level		Waveform 6 Waveform 7	2.0 2.0	5.3 4.3	6.0 5.5	2.0 2.0	7.0 6.5	ns

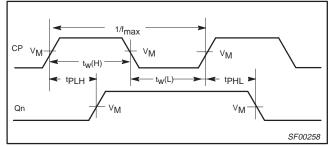
74F373/74F374

AC SET-UP REQUIREMENTS

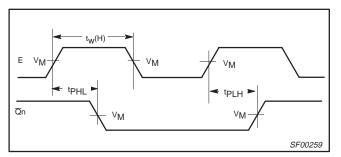
				LIMITS					
SYMBOL	PARAMETER	PARAMETER				°C V = 500 Ω	T _{amb} = 0 °C V _{CC} = +5.0 C _L = 50 pF,	UNIT	
			MIN	TYP	MAX	MIN	MAX		
t _{su} (H) t _{su} (L)	Set-up time, HIGH or LOW level Dn to E		Waveform 4	0 1.0			0 1.0		ns
t _h (H) t _h (L)	Hold time, HIGH or LOW level Dn to E	74F373	Waveform 4	3.0 3.0			3.0 3.0		ns
t _w (H)	E Pulse width, HIGH		Waveform 1	3.5			4.0		ns
t _{su} (H) t _{su} (L)	Set-up time, HIGH or LOW level Dn to CP		Waveform 5	2.0 2.0			2.0 2.0		ns
t _h (H) t _h (L)	Hold time, HIGH or LOW level Dn to CP	74F374	Waveform 5	0 0			0 0		ns
t _w (H) t _w (L)	CP Pulse width, HIGH or LOW		Waveform 5	3.5 4.0			3.5 4.0		ns

AC WAVEFORMS

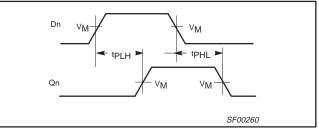
For all waveforms, $V_M = 1.5$ V. The shaded areas indicate when the input is permitted to change for predictable output performance.



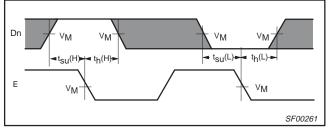
Waveform 1. Propagation delay for clock input to output, clock pulse widths, and maximum clock frequency



Waveform 2. Propagation delay for enable to output and enable pulse width



Waveform 3. Propagation delay for data to output

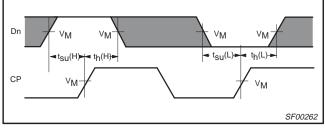


Waveform 4. Data set-up time and hold times

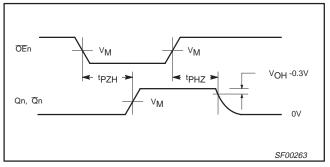
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AC WAVEFORMS (continued)

For all waveforms, $V_M = 1.5$ V. The shaded areas indicate when the input is permitted to change for predictable output performance.

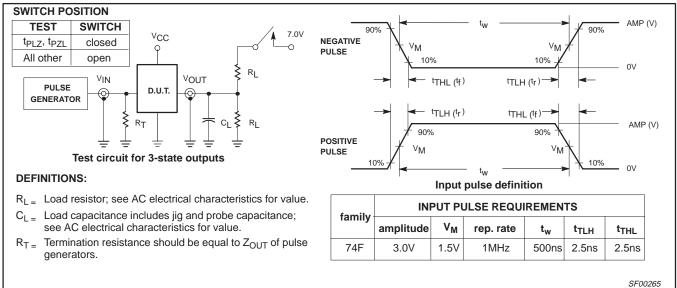


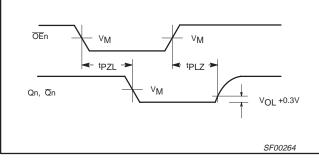
Waveform 5. Data set-up time and hold times



Waveform 6. 3-State output enable time to HIGH level and output disable time from HIGH level

TEST CIRCUIT AND WAVEFORMS

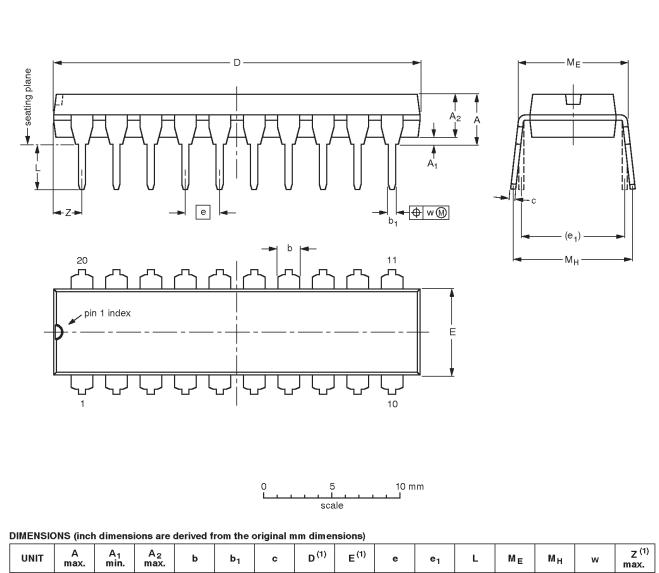




Waveform 7. 3-State output enable time to LOW level and output disable time from LOW level

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DIP20: plastic dual in-line package; 20 leads (300 mil) SOT146-1



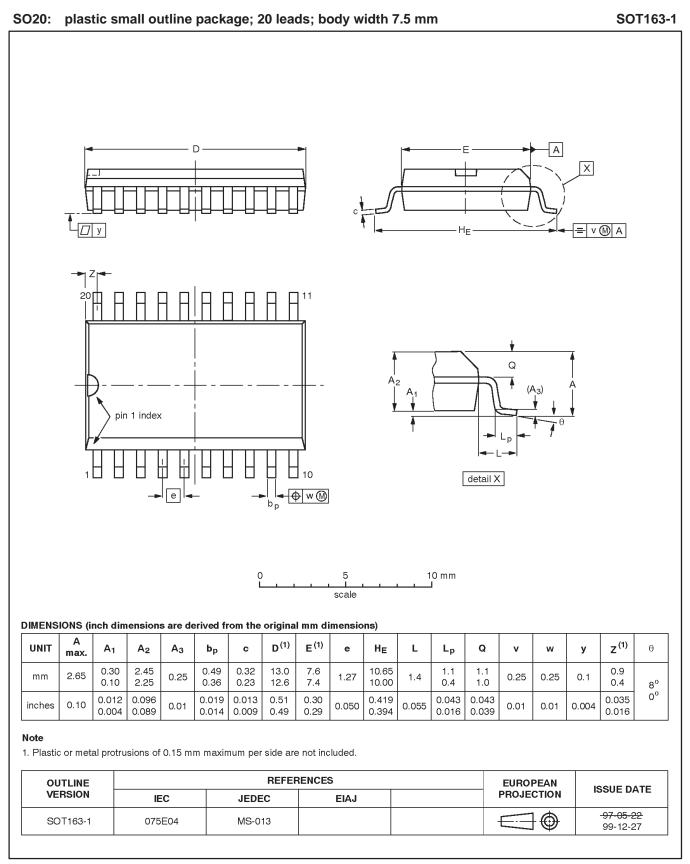
UNIT	A max.	A ₁ min.	A ₂ max.	b	b 1	С	D ⁽¹⁾	E ⁽¹⁾	е	e ₁	L	Μ _E	M _H	w	max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	0.36 0.23	26.92 26.54	6.40 6.22	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.0
inches	0.17	0.020	0.13	0.068 0.051	0.021 0.015	0.014 0.009	1.060 1.045	0.25 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.078

Note

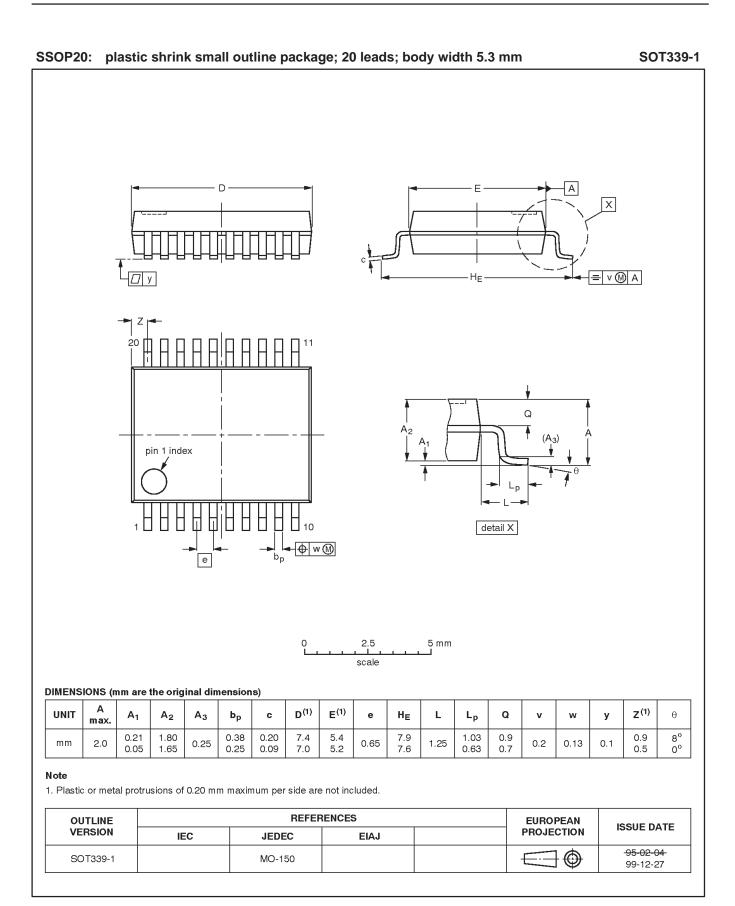
1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN	ISSUE DATE
	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT146-1		MS-001	SC-603			-95-05-24 99-12-27

74F373/74F374



74F373/74F374



2002 Nov 20

74F373/74F374

REVISION HISTORY

Rev	Date	Description	
_3	20021120	Product data; third version (9397 750 10758). Supersedes 74F373_374_2 dated 1994 Dec 05 (9397 750 05119).	
		Engineering Change Notice 853–0369 29206 (date: 20021115).	
		Modifications:	
		 Corrected ordering information table (from 'N74374DB' to '74F374DB'). 	
		 Add SSOP20 (SOT339-1) package outline drawing. 	
_2	19941205	Product data; second version (9397 750 05119).	
		Engineering Change Notice 853–0369 14383 (date: 19941205).	

Data sheet status

Level	Data sheet status ^[1]	Product status ^{[2] [3]}	Definitions
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
II	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
111	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

[1] Please consult the most recently issued data sheet before initiating or completing a design.

[2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.

[3] For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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